#### 3HE15212AA-OPC

Alcatel-Lucent Nokia® 3HE15212AA Compatible TAA Compliant 400GBase-LR8 QSFP-DD Transceiver (SMF, 8x50G PAM4, 10km, LC, DOM)

#### **Features**

- Hot-pluggable QSFP-DD Type 2 form factor
- Supports 425Gb/s aggregate bit rate
- Power dissipation < 13W
- Single 3.3V power supply
- Single-mode Fiber
- Aligned with IEEE 802.3bs
- Operating case temperature: 0C to 70C



## **Applications:**

- 400GBase Ethernet
- Access and Enterprise

### **Product Description**

This Alcatel-Lucent Nokia® 3HE15212AA compatible transceiver provides 400GBase-LR8 8x50G PAM4 throughput up to 10km over single-mode fiber (SMF) at a wavelength of 1310nm using an LC connector. It is built to MSA standards and is uniquely serialized and data-traffic and application tested to ensure that they will integrate into your network seamlessly. Digital optical monitoring (DOM) support is also present to allow access to real-time operating parameters. This transceiver is Trade Agreements Act (TAA) compliant. We stand behind the quality of our products and proudly offer a limited lifetime warranty.

## **Regulatory Compliance**

- ESD to the Electrical PINs: compatible with MIL-STD-883E Method 3015.4
- ESD to the LC Receptacle: compatible with IEC 61000-4-3
- EMI/EMC compatible with FCC Part 15 Subpart B Rules, EN55022:2010
- Laser Eye Safety compatible with FDA 21CFR, EN60950-1& EN (IEC) 60825-1,2
- RoHS compliant with EU RoHS 2.0 directive 2015/863/EU

## **Absolute Maximum Ratings**

Parameter	Symbol	Min.	Max.	Unit	Notes			
Power Supply Voltage	VCC	-0.5	4.0	V				
Storage Temperature	Ts	-40	+85	°C				
Case Operating Temperature	Тор	0	+70	°C				
Relative Humidity (non-condensing)	RH	15	85	%				
Receiver Damage Threshold, per Lane	P <sub>Rdmg</sub>	6.3		dBm				
Bit Rate (all wavelengths combined)	BR		425	Gb/s	1			
Bit Error Ratio	BER		2.4x10 <sup>-4</sup>		2			
Maximum Supported Distances								
Fiber Type								
SMF per G.652	Lmax1		10	km				

## Notes:

- 1. Supports 400GBASE-LR8 per IEEE P802.3bs.
- 2. As defined by IEEE P802.3bs.

# Electrical Characteristics (EOL, $T_{OP}$ = 0 to +70°C, $V_{CC}$ = 3.135 to 3.465 Volts)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Supply Voltage	Vcc	3.135	3.3	3.465	V	
Supply Current	Icc			3.83	А	
Module total power	Р			13	W	1
Transmitter			•			
Signaling Rate, each Lane	Vin, pp, diff	26.5625 ± 100	) ppm		GBd	
Differential data input voltage per lane	TP1a	900			mVpp	1
Differential input return loss		Per equation	(83E–5) IEEE80	02.3bm	dB	
Differential to common mode input return loss		Per equation	(83E–6) IEEE80	02.3bm	dB	
Differential termination mismatch				10	%	
Module stress input test		Per 120E.3.4.	1 IEEE802.3bs			3
Single-ended voltage tolerance range		-0.4		3.3	V	
DC common mode voltage		-350		2850	mV	4
Receiver						
Signaling Rate, each lane	gnaling Rate, each lane 26.5625 ± 100 ppm			GBd		
AC common-mode output voltage (RMS)				17.5	mV	
Differential output voltage				900	mV	
Near-end ESMW (Eye symmetry mask width)		0.265			UI	
Near-end Eye height, differential (min)		70			mV	
Far-end ESMW (Eye symmetry mask width)		0.2			UI	
Far-end Eye height, differential (min)		30			mV	
Far-end pre-cursor ISI ratio		-4.5		2.5	dB	
Differential output return loss		Per equation 83E-2 IEEE802.3bm				
Common to differential mode conversion return loss		Per equation 83E-3 IEEE802.3bm				
Differential termination mismatch				10	%	
Transition time (min, 20% to 80%)		9.5			ps	
DC common mode voltage (min)		-350		2850	mV	4

### Notes:

- 1. Maximum total power value is specified across the full temperature and voltage range.
- 2. With the exception to 120E.3.1.2 that the pattern is PRBS31Q or scrambled idle.
- 3. Meets specified BER
- 4. DC common mode voltage generated by the host. Specification includes effects of ground offset voltage.

# Optical Characteristics (EOL, $T_{OP}$ = 0 to +70°C, $V_{CC}$ = 3.135 to 3.465 Volts)

Meets 400GBASE-LR8 as being defined by IEEE P802.3bs

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Transmitter						
Signaling rate (each lane (range)		26.5625 ± 1	L00 ppm		GBd	
Modulation Format		PAM4				
Lane wavelengths (range)		1272.55 to 1274.54 1276.89 to 1278.89 1281.25 to 1283.27 1285.65 to 1287.68 1294.53 to 1296.59 1299.02 to 1301.09 1303.54 to 1305.63 1308.09 to 1310.19			nm	
Side-mode suppression ratio (SMSR)		30			dB	
Total average launch power				13.2	dBm	
Average launch power, each lane				5.3	dBm	1
Average launch power, each lane		-2.8			dBm	2
Outer Optical Modulation Amplitude (OMAouter), each lane		0.2		5.7	dBm	3
Difference in launch power between any two lanes (OMAouter)				4	dB	
Launch power in OMAouter minus TDECQ, each lane		-1.1			dBm	
Transmitter and dispersion eye closure for PAM4 (TDECQ), each lane				3.3	dB	
Average launch power of OFF transmitter, each lane				-30	dBm	
Extinction ratio		3.5			dB	
RIN <sub>15.1</sub> OMA				-132	dB/Hz	
Optical return loss tolerance				15.1	dB	
Transmitter reflectance				-26	dB	4
Receiver						
Signaling rate (each lane (range)		26.5625 ± 1	L00 ppm		GBd	
Modulation Format		PAM4				
Lane wavelengths (range)		1272.55 to 1274.54 1276.89 to 1278.89 1281.25 to 1283.27 1285.65 to 1287.68 1294.53 to 1296.59 1299.02 to 1301.09 1303.54 to 1305.63 1308.09 to 1310.19			nm	
Damage threshold, each lane		6.3			dBm	5
Average receive power, each lane				5.3	dBm	
Average receive power, each lane		-9.1			dBm	6
Receive power (OMAouter), each lane				5.7	dBm	

Difference in receive power between any two lanes (OMAouter)				4.5	dBm		
Receiver reflectance				-26	dB		
Receiver sensitivity (OMAouter), each lane				-7.1	dBm	7	
Stressed receiver sensitivity (OMAouter), each lane				-4.7	dBm	8	
Conditions for Stress Receiver Sensitivity Test							
Stressed eye closure for PAM4 (SECQ), lane under test		3.3			dB	9	
OMAouter of each aggressor lane		-0.2			dBm	9	

#### Notes:

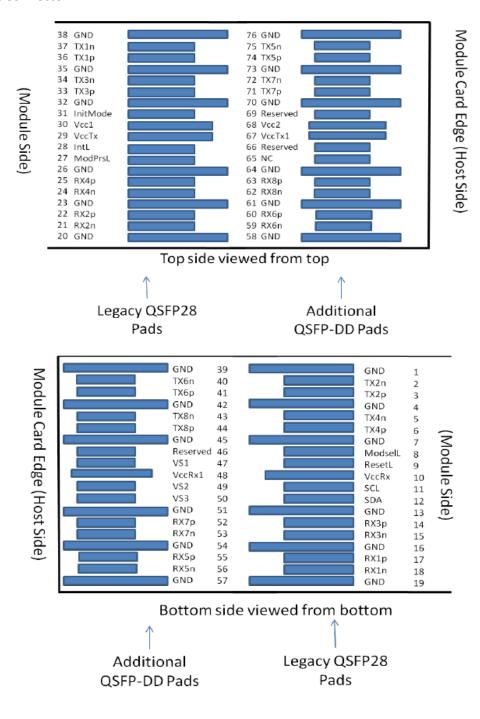
- 1. As the total average launch power limit has to be met, not all of the lanes can operate at the maximum average launch power, each lane.
- 2. Average launch power, each lane (min) is informative and not the principal indicator of signal strength. A transmitter with launch power below this value cannot be compliant; however, a value above this does not ensure compliance.
- 3. Even if the TDECQ < 1 dB, the OMAouter (min) must exceed this value
- 4. Transmitter reflectance is defined looking into the transmitter
- 5. The receiver shall be able to tolerate, without damage, continuous exposure to an optical input signal having this average power level.
- 6. Average receive power, each lane (min) is informative and not the principal indicator of signal strength. A received power below this value cannot be compliant; however, a value above this does not ensure compliance.
- 7. Receiver sensitivity (OMAouter), each lane (max) is informative.
- 8. Measured with conformance test signal at TP3 (see 122.8.9) for the BER specified in 122.1.1.
- 9. These test conditions are for measuring stressed receiver sensitivity. They are not characteristics of the receiver.

**Pin Descriptions** 

Pin L	Pin Descriptions						
Pin	Logic	Symbol	Name/Descriptions	Plug Sequence			
1		GND	Ground	1B			
2	CML-I	Tx2n	Transmitter Inverted Data Input	3B			
3	CML-I	Tx2p	Transmitter Non-Inverted Data Input	3B			
4		GND	Ground	1B			
5	CML-I	Tx4n	Transmitter Inverted Data Input	3B			
6	CML-I	Tx4p	Transmitter Non-Inverted Data Input	3B			
7		GND	Ground	1B			
8	LVTTL-I	ModSelL	Module Select	3B			
9	LVTTL-I	ResetL	Module Reset	3B			
10		VccRx	+3.3V Power Supply Receiver	2B			
11	LVCMOS-I/O	SCL	2-wire serial interface clock	3B			
12	LVCMOS-I/O	SDA	2-wire serial interface data	3B			
13		GND	Ground	1B			
14	CML-O	Rx3p	Receiver Non-Inverted Data Output	3B			
15	CML-O	Rx3n	Receiver Inverted Data Output	3B			
16	GND	Ground	1B				
17	CML-O	Rx1p	Receiver Non-Inverted Data Output	3B			
18	CML-O	Rx1n	Receiver Inverted Data Output	3B			
19		GND	Ground	1B			
20		GND	Ground	1B			
21	CML-O	Rx2n	Receiver Inverted Data Output	3B			
22	CML-O	Rx2p	Receiver Non-Inverted Data Output	3B			
23		GND	Ground	1B			
24	CML-O	Rx4n	Receiver Inverted Data Output	3B			
25	CML-O	Rx4p	Receiver Non-Inverted Data Output	3B			
26		GND	Ground	1B			
27	LVTTL-O	ModPrsL	Module Present	3B			
28	LVTTL-O	IntL	Interrupt	3B			
29		VccTx	+3.3V Power supply transmitter	2B			
30		Vcc1	+3.3V Power supply	2B			
31	LVTTL-I	InitMode	Initialization mode; In legacy QSFP applications, the InitMode pad is called LPMODE	3B			
32		GND	Ground	1B			
33	CML-I	Тх3р	Transmitter Non-Inverted Data Input	3B			
34	CML-I	Tx3n	Transmitter Inverted Data Input	3B			
35		GND	Ground	1B			
36	CML-I	Tx1p	Transmitter Non-Inverted Data Input	3B			
37	CML-I	Tx1n	Transmitter Inverted Data Input	3B			
38		GND	Ground	1B			
39		GND	Ground	1A			
40	CML-I	Tx6n	Transmitter Inverted Data Input	3A			

41	CML-I	Тх6р	Transmitter Non-Inverted Data Input	3A
42		GND	Ground	1A
43	CML-I	Tx8n	Transmitter Inverted Data Input	3A
44	CML-I	Тх8р	Transmitter Non-Inverted Data Input	3A
45		GND	Ground	1A
46		Reserved	For future use	3A
47		VS1	Module Vendor Specific 1	3A
48		VccRx1	3.3V Power Supply	2A
49		VS2	Module Vendor Specific 2	3A
50		VS3	Module Vendor Specific 3	3A
51		GND	Ground	1A
52	CML-O	Rx7p	Receiver Non-Inverted Data Output	3A
53	CML-O	Rx7n	Receiver Inverted Data Output	3A
54		GND	Ground	1A
55	CML-O	Rx5p	Receiver Non-Inverted Data Output	3A
56	CML-O	Rx5n	Receiver Inverted Data Output	3A
57		GND	Ground	1A
58		GND	Ground	1A
59	CML-O	Rx6n	Receiver Inverted Data Output	3A
60	CML-O	Rx6p	Receiver Non-Inverted Data Output	3A
61		GND	Ground	1A
62	CML-O	Rx8n	Receiver Inverted Data Output	3A
63	CML-O	Rx8p	Receiver Non-Inverted Data Output	3A
67		GND	Ground	1A
68		NC	No Connect	3A
69		Reserved	For future use	3A
70		VccTx1	3.3V Power Supply	2A
71		Vcc2	3.3V Power Supply	2A
72		Reserved	For Future Use	3A
73		GND	Ground	1A
74	CML-I	Тх7р	Transmitter Non-Inverted Data Input	3A
75	CML-I	Tx7n	Transmitter Inverted Data Input	3A
76		GND	Ground	1A

## **MSA Compliant Connector**



# **Mechanical Specifications**

